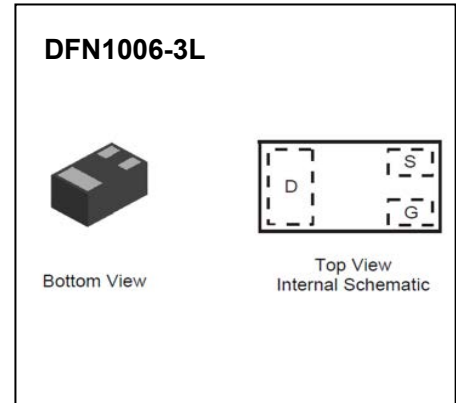




**DFN1006-3L Plastic-Encapsulate MOSFETs**

**CJBA3134K N-Channel MOSFET**

$V_{(BR)DSS}$	$R_{DS(on)MAX}$	$I_D$
20V	500mΩ@4.5V	0.75A
	700mΩ@2.5V	
	900mΩ@1.8V	



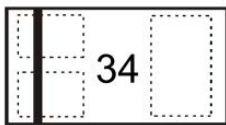
**FEATURE**

- Lead Free Product is Acquired
- Surface Mount Package
- N-Channel Switch with Low  $R_{DS(on)}$
- Operated at Low Logic Level Gate Drive
- ESD Protected Gate

**APPLICATION**

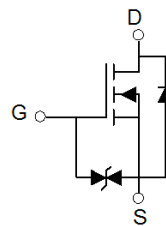
- Load/ Power Switching
- Interfacing Switching
- Battery Management for Ultra Small Portable Electronics
- Logic Level Shift

**MARKING:**



Top View  
Bar Denotes Gate and Source Side

**Equivalent Circuit**



**ABSOLUTE MAXIMUM RATINGS ( $T_a=25^\circ\text{C}$  unless otherwise noted)**

Parameter	Symbol	Value	Unit
Drain-Source Voltage	$V_{DS}$	20	V
Typical Gate-Source Voltage	$V_{GS}$	±12	V
Continuous Drain Current (note 1)	$I_D$	0.75	A
Pulsed Drain Current ( $t_p=10\mu\text{s}$ )	$I_{DM}$	1.8	A
Power Dissipation (note 1)	$P_D$	275	mW
Thermal Resistance from Junction to Ambient (note 1)	$R_{\theta JA}$	455	$^\circ\text{C}/\text{W}$
Operation Junction and Storage Temperature Range	$T_J, T_{STG}$	-55~ 150	$^\circ\text{C}$
Lead Temperature for Soldering Purposes(1/8" from case for 10 s)	$T_L$	260	$^\circ\text{C}$

## MOSFET ELECTRICAL CHARACTERISTICS

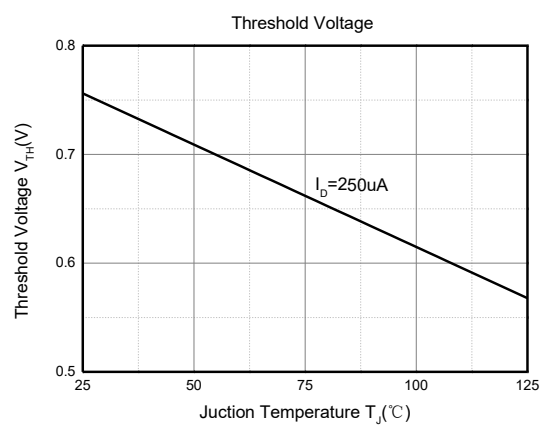
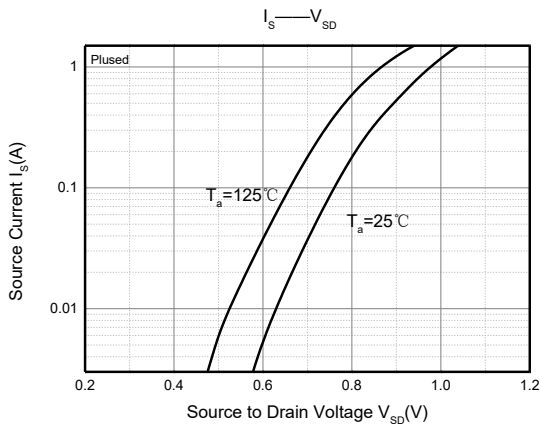
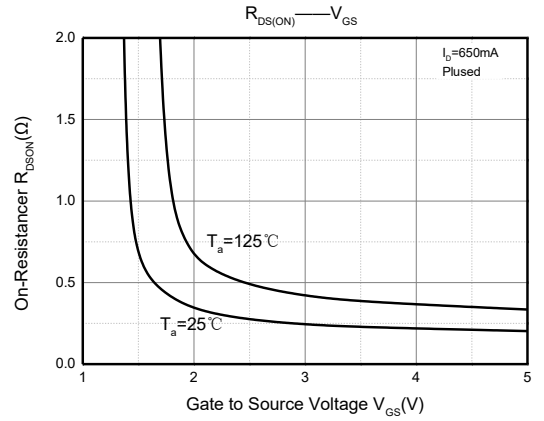
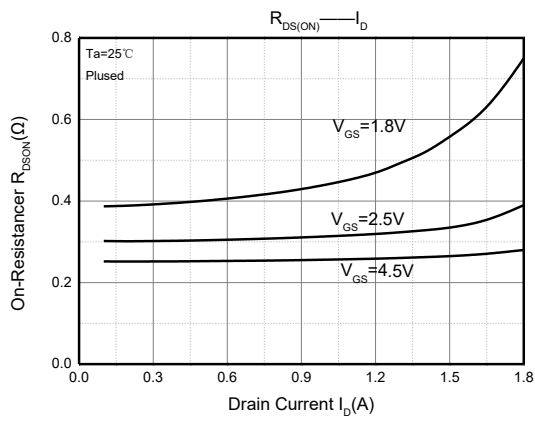
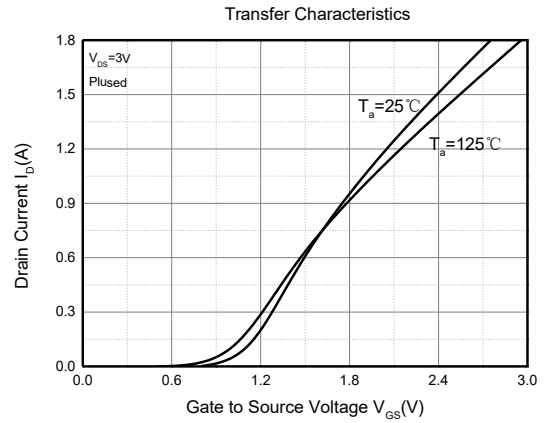
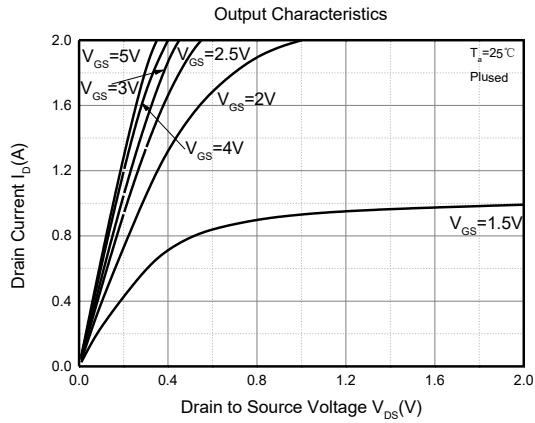
$T_a=25^{\circ}\text{C}$  unless otherwise noted

Parameter	Symbol	Test Condition	Min	Type	Max	Unit
<b>Static Characteristics</b>						
Drain-source breakdown voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_D = 250\mu A$	20			V
Zero gate voltage drain current	$I_{DSS}$	$V_{DS} = 20V, V_{GS} = 0V$			1	$\mu A$
Gate-body leakage current	$I_{GSS}$	$V_{GS} = \pm 10V, V_{DS} = 0V$			$\pm 20$	$\mu A$
Gate threshold voltage <sup>(2)</sup>	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250\mu A$	0.35	0.75	1.1	V
Drain-source on-resistance <sup>(2)</sup>	$R_{DS(on)}$	$V_{GS} = 4.5V, I_D = 150mA$		250	500	m $\Omega$
		$V_{GS} = 2.5V, I_D = 150mA$		300	700	
		$V_{GS} = 1.8V, I_D = 150mA$		370	900	
		$V_{GS} = 1.5V, I_D = 20mA$		460		
		$V_{GS} = 1.2V, I_D = 10mA$		1200		
Forward tranconductance	$g_{FS}$	$V_{DS} = 10V, I_D = 150mA$	150			mS
<b>Dynamic characteristics<sup>(4)</sup></b>						
Input Capacitance	$C_{iss}$	$V_{DS} = 16V, V_{GS} = 0V, f = 1MHz$		79	120	pF
Output Capacitance	$C_{oss}$			13	20	
Reverse Transfer Capacitance	$C_{rss}$			9	15	
<b>Switching Characteristics<sup>(4)</sup></b>						
Turn-on delay time <sup>(3)</sup>	$t_{d(on)}$	$V_{DS} = 10V, I_D = 500mA,$ $V_{GS} = 4.5V, R_G = 10\Omega$		6.7		ns
Turn-on rise time <sup>(3)</sup>	$t_r$			4.8		
Turn-off delay time <sup>(3)</sup>	$t_{d(off)}$			17.3		
Turn-off fall time <sup>(3)</sup>	$t_f$			7.4		
<b>Source-Drain Diode characteristics</b>						
Diode Forward voltage <sup>(3)</sup>	$V_{SD}$	$I_S = 0.15A, V_{GS} = 0V$			1.2	V

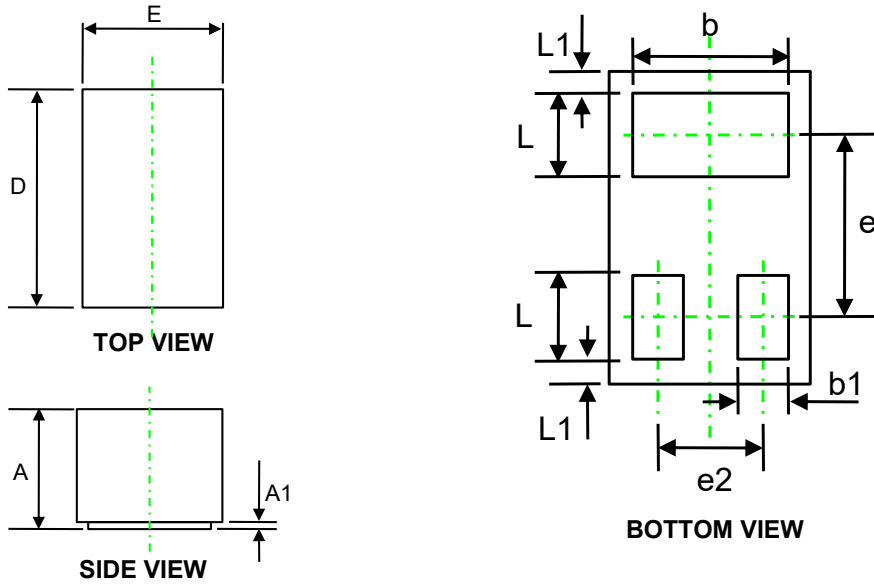
### Notes:

1. Surface mounted on FR4 board using 1 square inch pad size, 1oz copper.
2. Pulse Test : Pulse Width=300 $\mu s$ , Duty Cycle=2%.
3. Switching characteristics are independent of operating junction temperatures.
4. Guaranteed by design, not subject to producing.

# Typical Characteristics

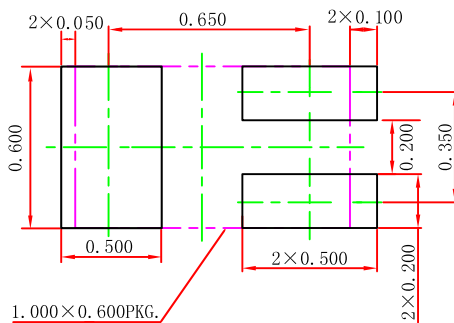


## DFN1006-3L Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.400	0.550	0.016	0.022
A1	0.000	0.050	0.000	0.002
D	0.950	1.050	0.037	0.041
E	0.550	0.650	0.022	0.026
b	0.450	0.550	0.018	0.022
e	0.650 REF.		0.026 REF.	
e2	0.350 REF.		0.014 REF.	
L1	0.050 REF.		0.002 REF.	
L	0.200	0.300	0.008	0.012
b1	0.100	0.200	0.004	0.008

## DFN1006-3L Suggested Pad Layout



### Note:

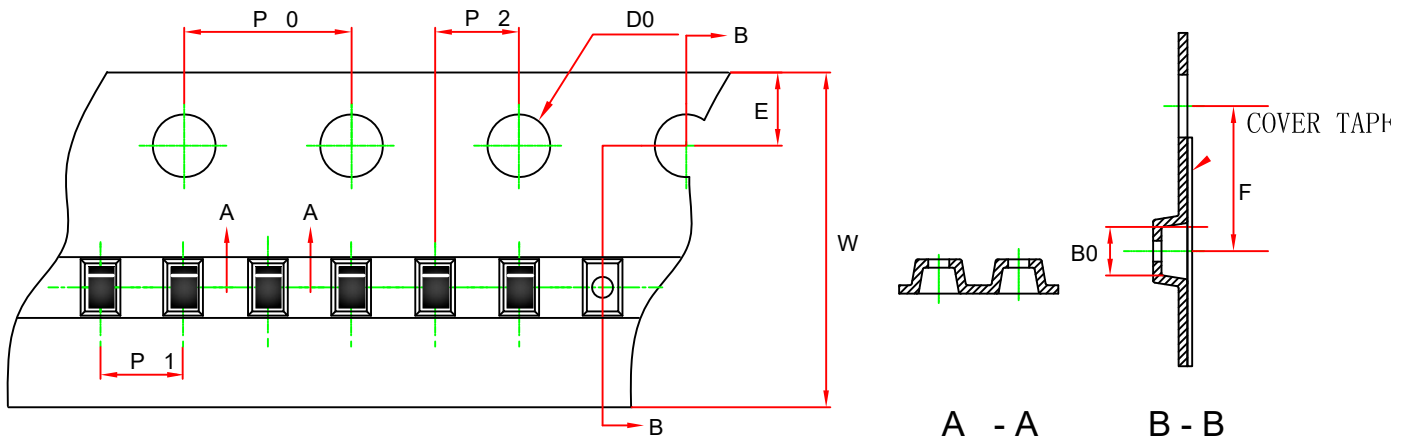
1. Controlling dimension: in millimeters.
2. General tolerance:  $\pm 0.050$  mm.
3. The pad layout is for reference purposes only.

### NOTICE

JSCJ reserves the right to make modifications, enhancements, improvements, corrections or other changes without further notice to any product herein. JSCJ does not assume any liability arising out of the application or use of any product described herein.

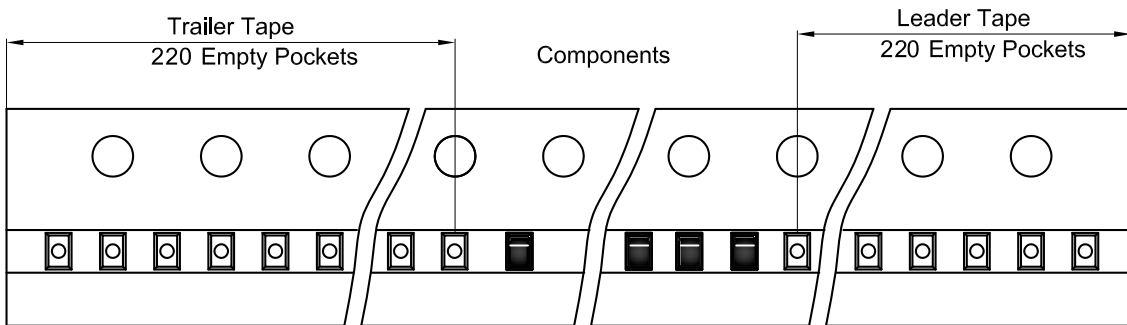
# DFN1006-3L Tape and Reel

## DFN1006-3L Embossed Carrier Tape

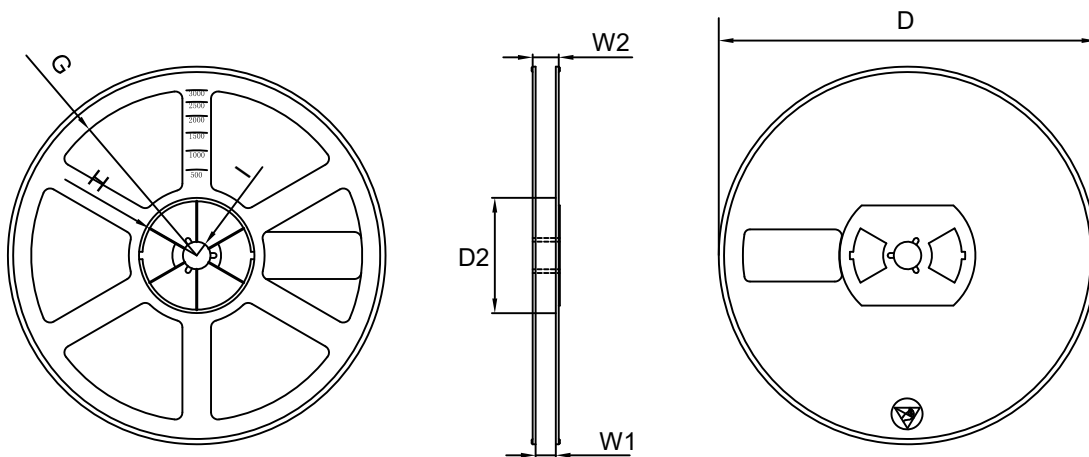


Dimensions In Millimeters (mm)								
Pkg type	B0	P0	P1	P2	E	F	W	D0
DFN1006-3L	1.11	4.00	2.00	2.00	1.75	3.50	8.00	1.55
Tolerance	+/-0.06	+/-0.1	+/-0.1	+/-0.1	+/-0.1	+/-0.1	+/-0.3	+/-0.1

## DFN1006-3L Tape Leader and Trailer



## DFN1006-3L Reel



Symbol	Dimensions In Millimeters (mm)						
	D	D2	G	H	I	W1	W2
7" Dia	Φ178.00	54.50	R78.00	R25.6	R6.5	9.50	12.30
Tolerance	+/-2	+/-1	+/-1	+/-1	+/-1	+/-2	+/-1.5

REEL	Reel Size	Box	Box size(mm)	Carton	Carton Size(mm)
10000 pcs	7 inch	150000 pcs	220×220×210	600000 pcs	450×450×240